

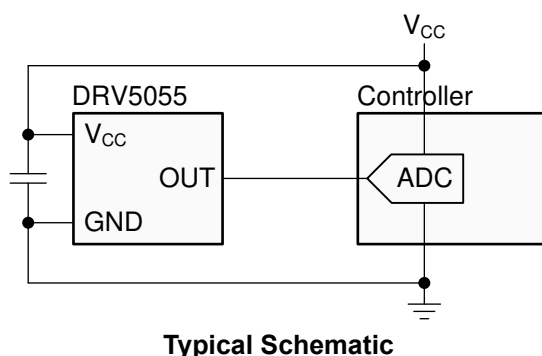
DRV5055 Ratiometric Linear Hall Effect Sensor

1 Features

- Ratiometric Linear Hall Effect Magnetic Sensor
- Operates From 3.3-V and 5-V Power Supplies
- Analog Output With $V_{CC} / 2$ Quiescent Offset
- Magnetic Sensitivity Options (At $V_{CC} = 5\text{ V}$):
 - A1/Z1: 100 mV/mT, $\pm 21\text{-mT}$ Range
 - A2/Z2: 50 mV/mT, $\pm 42\text{-mT}$ Range
 - A3/Z3: 25 mV/mT, $\pm 85\text{-mT}$ Range
 - A4/Z4: 12.5 mV/mT, $\pm 169\text{-mT}$ Range
- Fast 20-kHz Sensing Bandwidth
- Low-Noise Output With $\pm 1\text{-mA}$ Drive
- Compensation For Magnet Temperature Drift for A1/A2/A3/A4 Versions and None for Z1/Z2/Z3/Z4 Versions
- Standard Industry Packages:
 - Surface-Mount SOT-23
 - Through-Hole TO-92

2 Applications

- Precise Position Sensing
- Industrial Automation and Robotics
- Home Appliances
- Gamepads, Pedals, Keyboards, Triggers
- Height Leveling, Tilt and Weight Measurement
- Fluid Flow Rate Measurement
- Medical Devices
- Absolute Angle Encoding
- Current Sensing



3 Description

The DRV5055 is a linear Hall effect sensor that responds proportionally to magnetic flux density. The device can be used for accurate position sensing in a wide range of applications.

The device operates from 3.3-V or 5-V power supplies. When no magnetic field is present, the analog output drives half of V_{CC} . The output changes linearly with the applied magnetic flux density, and four sensitivity options enable maximal output voltage swing based on the required sensing range. North and south magnetic poles produce unique voltages.

Magnetic flux perpendicular to the top of the package is sensed, and the two package options provide different sensing directions.

The device uses a ratiometric architecture that can eliminate error from V_{CC} tolerance when the external analog-to-digital converter (ADC) uses the same V_{CC} for its reference. Additionally, the device features magnet temperature compensation to counteract how magnets drift for linear performance across a wide -40°C to 125°C temperature range. Device options for no temperature compensation of magnet drift are also available.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
DRV5055	SOT-23 (3)	2.92 mm × 1.30 mm
	TO-92 (3)	4.00 mm × 3.15 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

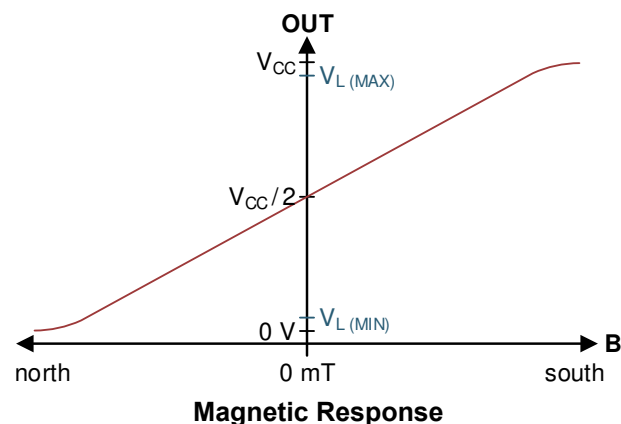


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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (June 2020) to Revision B (April 2021)	Page
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Changed the absolute maximum operating junction temperature from: 150°C to: 170°C.....	4
• Removed the Product Preview tablenote from the <i>Magnetic Characteristics</i> table.....	5
Changes from Revision * (January 2018) to Revision A (June 2020)	Page
• Added Zero TC sensitivity options to the data sheet.....	1
• Added Zero TC information to the <i>Electrical Characteristics</i>	5
• Added Zero TC information to the <i>Magnetic Characteristics</i> table.....	5
• Added graphs for DV5055Z1/Z2/Z3/Z4 options in the <i>Typical Characteristics</i> section.....	6
• Updated S_{TC} definition in Equation 1	10
• Updated the <i>Sensitivity Temperature Compensation for Magnets</i> section for Zero TC options.....	12

5 Pin Configuration and Functions

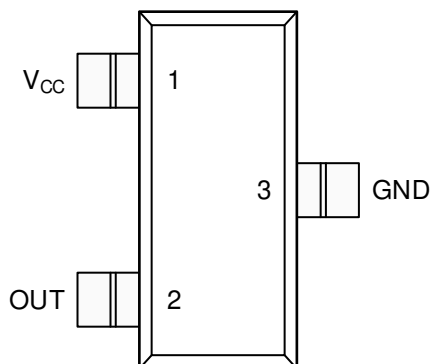


Figure 5-1. DBZ Package 3-Pin SOT-23 Top View

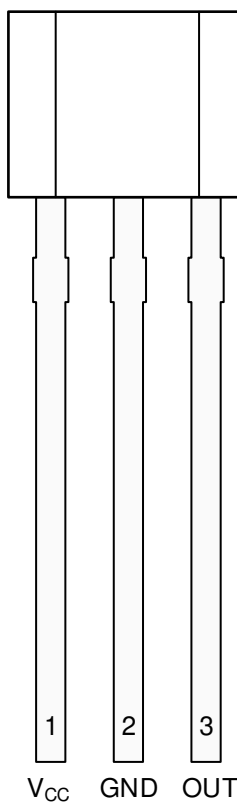


Figure 5-2. LPG Package 3-Pin TO-92 Top View

Table 5-1. Pin Functions

NAME	PIN		I/O	DESCRIPTION
	SOT-23	TO-92		
V _{CC}	1	1	—	Power supply. TI recommends connecting this pin to a ceramic capacitor to ground with a value of at least 0.01 μ F.
OUT	2	3	O	Analog output
GND	3	2	—	Ground reference

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Power supply voltage	V _{CC}	−0.3	7	V
Output voltage	OUT	−0.3	V _{CC} + 0.3	V
Magnetic flux density, B _{MAX}		Unlimited		T
Operating junction temperature, T _J		−40	170	°C
Storage temperature, T _{stg}		−65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

		VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2500	V
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±750	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC} Power-supply voltage ⁽¹⁾		3	3.63	V
		4.5	5.5	
I _O Output continuous current		−1	1	mA
T _A Operating ambient temperature ⁽²⁾		−40	125	°C

- (1) There are two isolated operating V_{CC} ranges. For more information see the [Operating V_{CC} Ranges](#) section.

- (2) Power dissipation and thermal limits must be observed.

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DRV5055		UNIT
		SOT-23 (DBZ)	TO-92 (LPG)	
		3 PINS	3 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	170	121	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	66	67	°C/W
R _{θJB}	Junction-to-board thermal resistance	49	97	°C/W
Y _{JT}	Junction-to-top characterization parameter	1.7	7.6	°C/W
Y _{JB}	Junction-to-board characterization parameter	48	97	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics

for $V_{CC} = 3\text{ V}$ to 3.63 V and 4.5 V to 5.5 V , over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
I_{CC} Operating supply current			6	10	mA
t_{ON} Power-on time (see Figure 7-4)	$B = 0\text{ mT}$, no load on OUT		175	330	μs
f_{BW} Sensing bandwidth			20		kHz
t_d Propagation delay time	From change in B to change in OUT		10		μs
B_{ND} Input-referred RMS noise density	$V_{CC} = 5\text{ V}$		130		$\text{nT}/\sqrt{\text{Hz}}$
	$V_{CC} = 3.3\text{ V}$		215		
B_N Input-referred noise	$B_{ND} \times 6.6 \times \sqrt{20\text{ kHz}}$	$V_{CC} = 5\text{ V}$	0.12		mT_{PP}
		$V_{CC} = 3.3\text{ V}$	0.2		
V_N Output-referred noise ⁽²⁾	$B_N \times S$	DRV5055A1/Z1	12		mV_{PP}
		DRV5055A2/Z2	6		
		DRV5055A3/Z3	3		
		DRV5055A4/Z4	1.5		

(1) B is the applied magnetic flux density.

(2) V_N describes voltage noise on the device output. If the full device bandwidth is not needed, noise can be reduced with an RC filter.

6.6 Magnetic Characteristics

for $V_{CC} = 3\text{ V}$ to 3.63 V and 4.5 V to 5.5 V , over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS ⁽¹⁾		MIN	TYP	MAX	UNIT
V _Q	Quiescent voltage	B = 0 mT, T _A = 25°C	V _{CC} = 5 V	2.43	2.5	2.57	V
			V _{CC} = 3.3 V	1.59	1.65	1.71	
V _{QΔT}	Quiescent voltage temperature drift	B = 0 mT, T _A = −40°C to 125°C versus 25°C		±1% × V _{CC}			V
V _{QRE}	Quiescent voltage ratiometry error ⁽²⁾			±0.2%			
V _{QΔL}	Quiescent voltage lifetime drift	High-temperature operating stress for 1000 hours		< 0.5%			
S	Sensitivity	V _{CC} = 5 V, T _A = 25°C	DRV5055A1/Z1	95	100	105	mV/mT
			DRV5055A2/Z2	47.5	50	52.5	
			DRV5055A3/Z3	23.8	25	26.2	
			DRV5055A4/Z4	11.9	12.5	13.2	
		V _{CC} = 3.3 V, T _A = 25°C	DRV5055A1/Z1	57	60	63	
			DRV5055A2/Z2	28.5	30	31.5	
			DRV5055A3/Z3	14.3	15	15.8	
			DRV5055A4/Z4	7.1	7.5	7.9	
B _L	Linear magnetic sensing range ^{(3) (4)}	V _{CC} = 5 V, T _A = 25°C	DRV5055A1/Z1	±21			mT
			DRV5055A2/Z2	±42			
			DRV5055A3/Z3	±85			
			DRV5055A4/Z4	±169			
		V _{CC} = 3.3 V, T _A = 25°C	DRV5055A1/Z1	±22			
			DRV5055A2/Z2	±44			
			DRV5055A3/Z3	±88			
			DRV5055A4/Z4	±176			
V _L	Linear range of output voltage ⁽⁴⁾			0.2	V _{CC} − 0.2		V
S _{TC}	Sensitivity temperature compensation for magnets ⁽⁵⁾	DRV5055A1, DRV5055A2, DRV5055A3, DRV5055A4		0.12			%/°C

for $V_{CC} = 3\text{ V}$ to 3.63 V and 4.5 V to 5.5 V , over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS ⁽¹⁾	MIN	TYP	MAX	UNIT
S_{TCz} Sensitivity temperature compensation for magnets ⁽⁵⁾	DRV5055Z1, DRV5055Z2, DRV5055Z3, DRV5055Z4		0		%/°C
S_{LE} Sensitivity linearity error ⁽⁴⁾	V_{OUT} is within V_L		$\pm 1\%$		
S_{SE} Sensitivity symmetry error ⁽⁴⁾	V_{OUT} is within V_L		$\pm 1\%$		
S_{RE} Sensitivity ratiometry error ⁽²⁾	$T_A = 25^\circ\text{C}$, with respect to $V_{CC} = 3.3\text{ V}$ or 5 V	-2.5%		2.5%	
$S_{\Delta L}$ Sensitivity lifetime drift	High-temperature operating stress for 1000 hours		<0.5%		

- (1) B is the applied magnetic flux density.
 (2) See the [Ratiometric Architecture](#) section.
 (3) B_L describes the minimum linear sensing range at 25°C taking into account the maximum V_Q and Sensitivity tolerances.
 (4) See the [Sensitivity Linearity](#) section.
 (5) S_{TC} describes the rate the device increases Sensitivity with temperature. For more information, see the [Sensitivity Temperature Compensation for Magnets](#) section.

6.7 Typical Characteristics

for $T_A = 25^\circ\text{C}$ (unless otherwise noted)

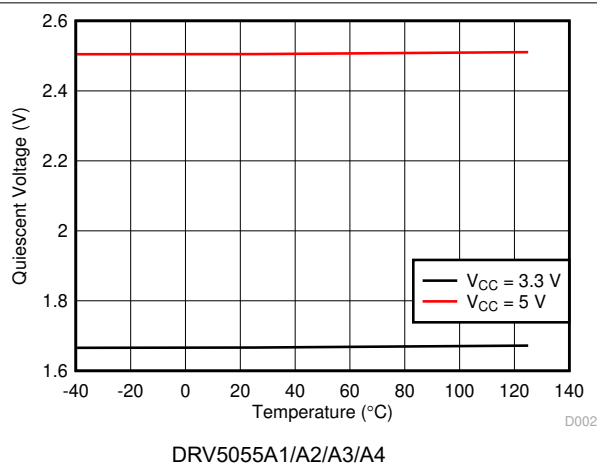


Figure 6-1. Quiescent Voltage vs. Temperature

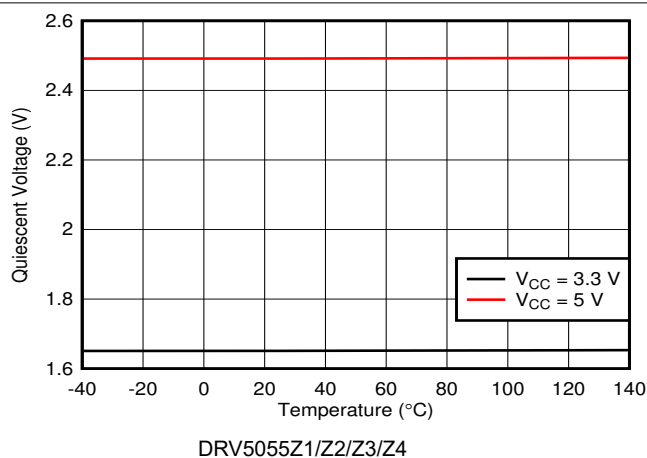


Figure 6-2. Quiescent Voltage vs. Temperature

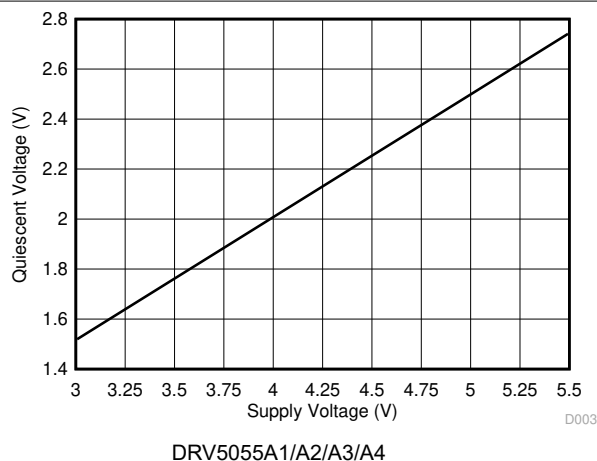


Figure 6-3. Quiescent Voltage vs. Supply Voltage

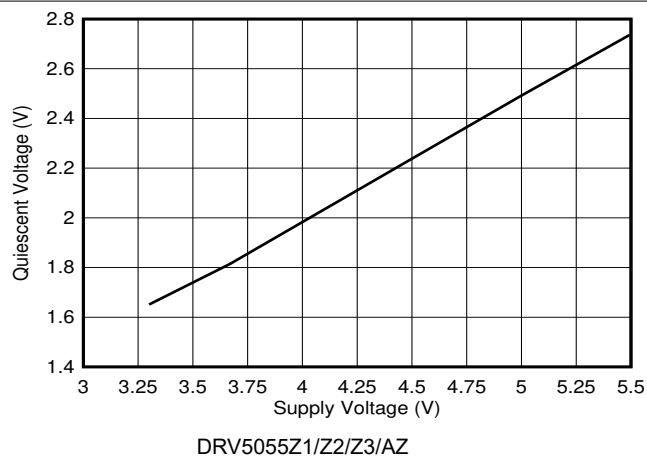


Figure 6-4. Quiescent Voltage vs. Supply Voltage

6.7 Typical Characteristics (continued)

for $T_A = 25^\circ\text{C}$ (unless otherwise noted)

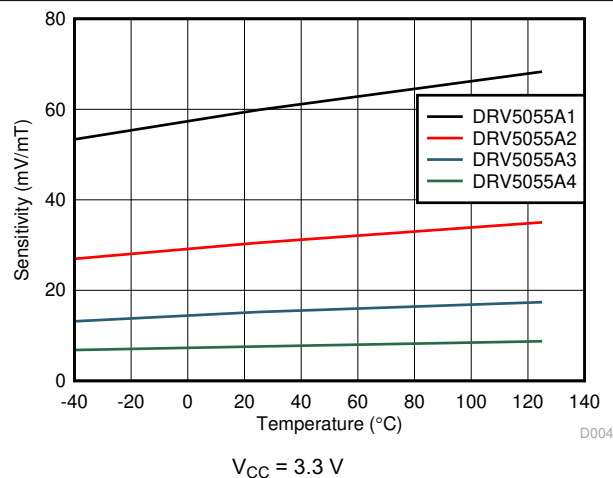


Figure 6-5. Sensitivity vs. Temperature

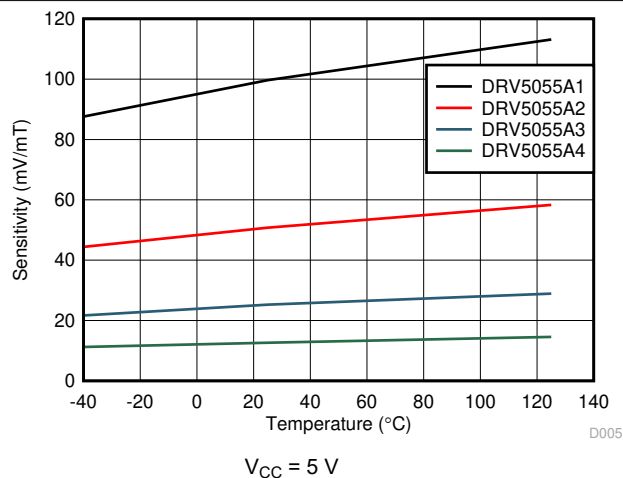


Figure 6-6. Sensitivity vs. Temperature

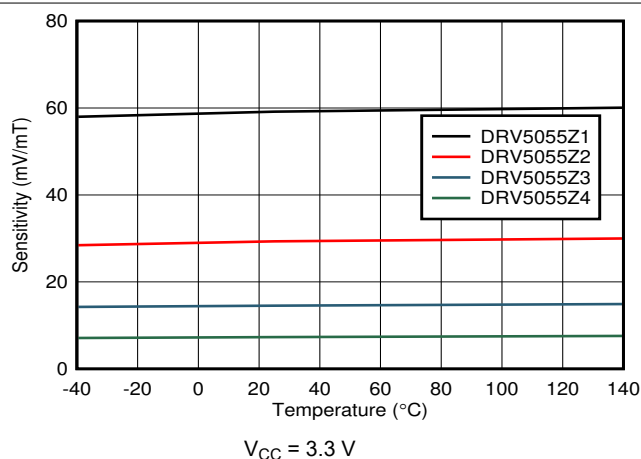


Figure 6-7. Sensitivity vs. Temperature

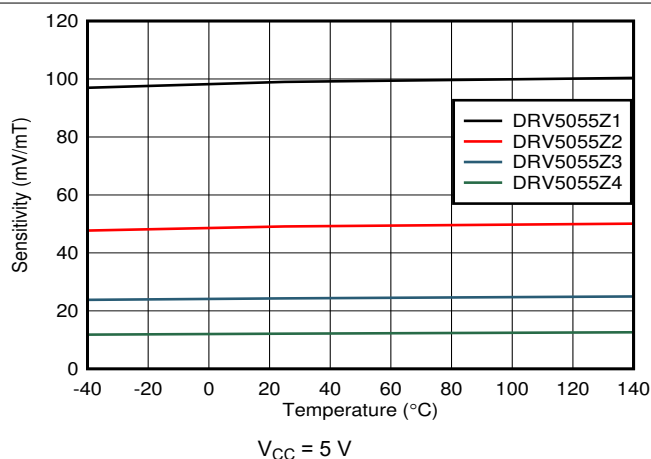


Figure 6-8. Sensitivity vs. Temperature

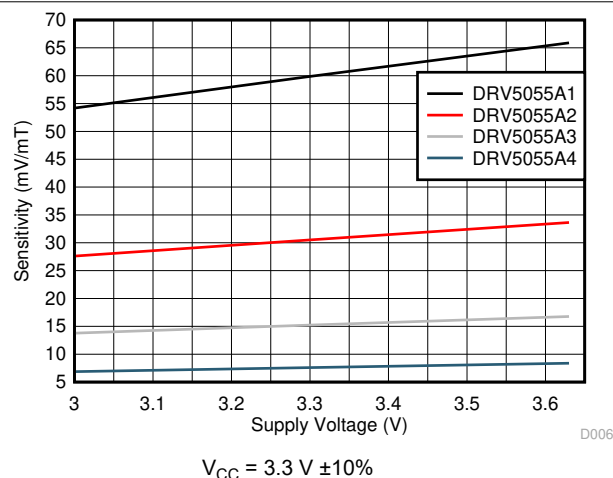


Figure 6-9. Sensitivity vs. Supply Voltage

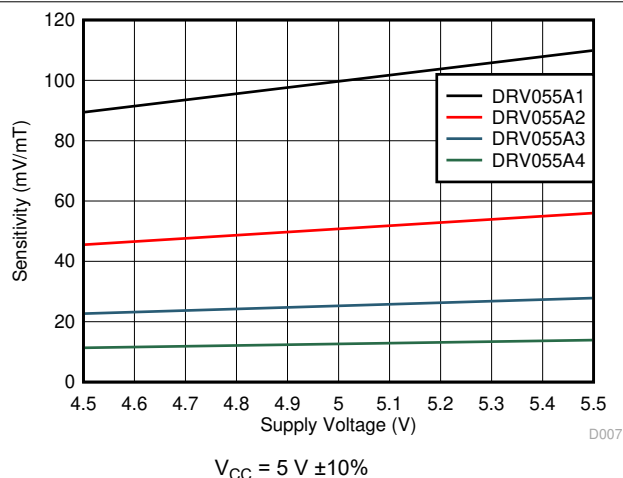


Figure 6-10. Sensitivity vs. Supply Voltage

6.7 Typical Characteristics (continued)

for $T_A = 25^\circ\text{C}$ (unless otherwise noted)

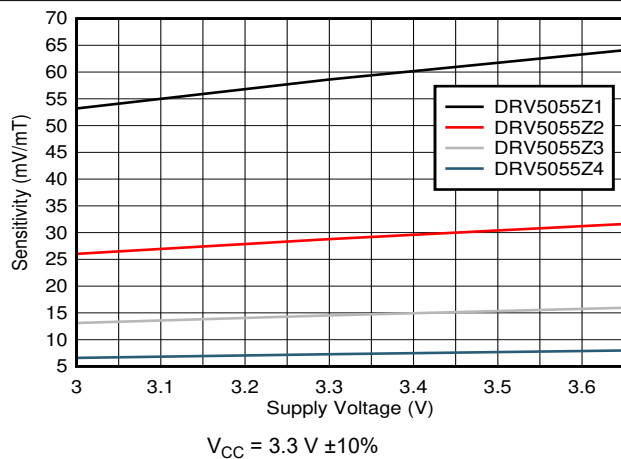


Figure 6-11. Sensitivity vs. Supply Voltage

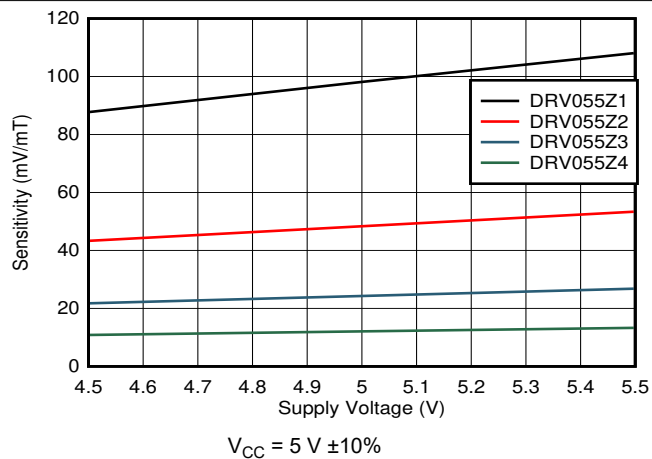


Figure 6-12. Sensitivity vs. Supply Voltage

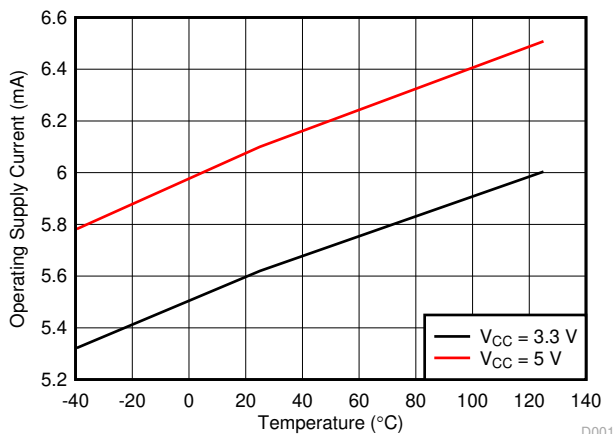


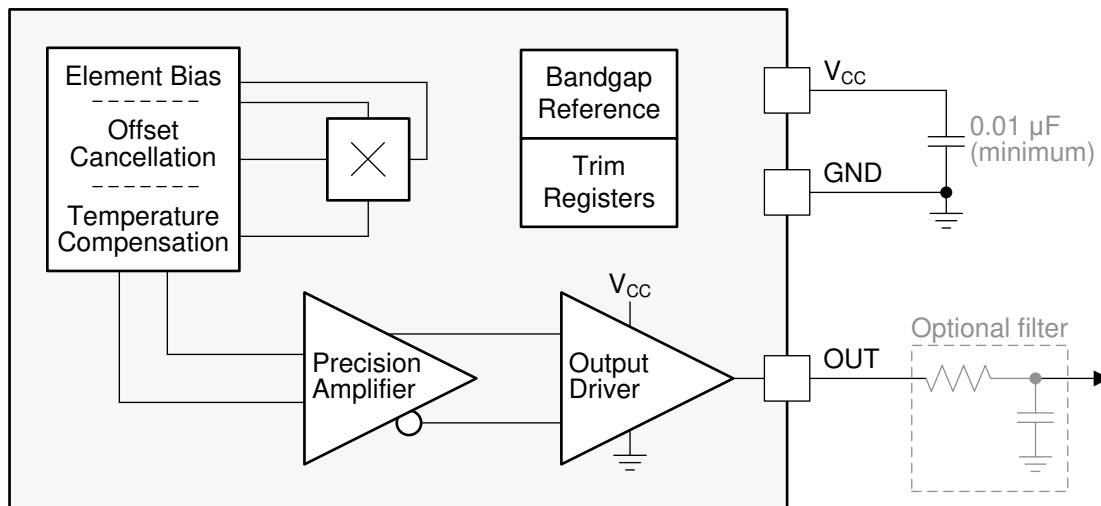
Figure 6-13. Operating Supply Current vs. Temperature

7 Detailed Description

7.1 Overview

The DRV5055 is a 3-pin linear Hall effect sensor with fully integrated signal conditioning, temperature compensation circuits, mechanical stress cancellation, and amplifiers. The device operates from 3.3-V and 5-V ($\pm 10\%$) power supplies, measures magnetic flux density, and outputs a proportional analog voltage that is referenced to V_{CC} .

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Magnetic Flux Direction

As shown in Figure 7-1, the DRV5055 is sensitive to the magnetic field component that is perpendicular to the top of the package.

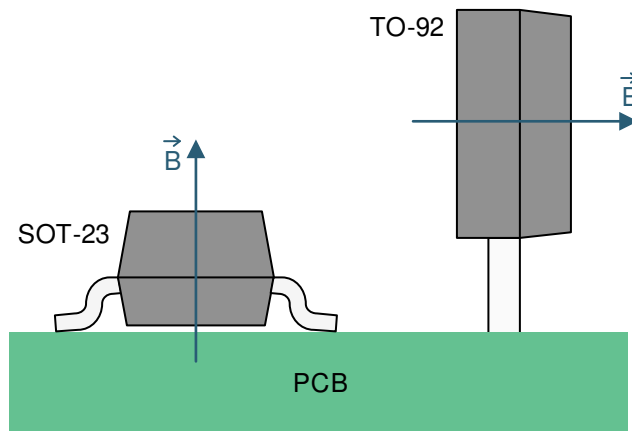


Figure 7-1. Direction of Sensitivity

Magnetic flux that travels from the bottom to the top of the package is considered positive in this document. This condition exists when a south magnetic pole is near the top (marked-side) of the package. Magnetic flux that travels from the top to the bottom of the package results in negative millitesla values.

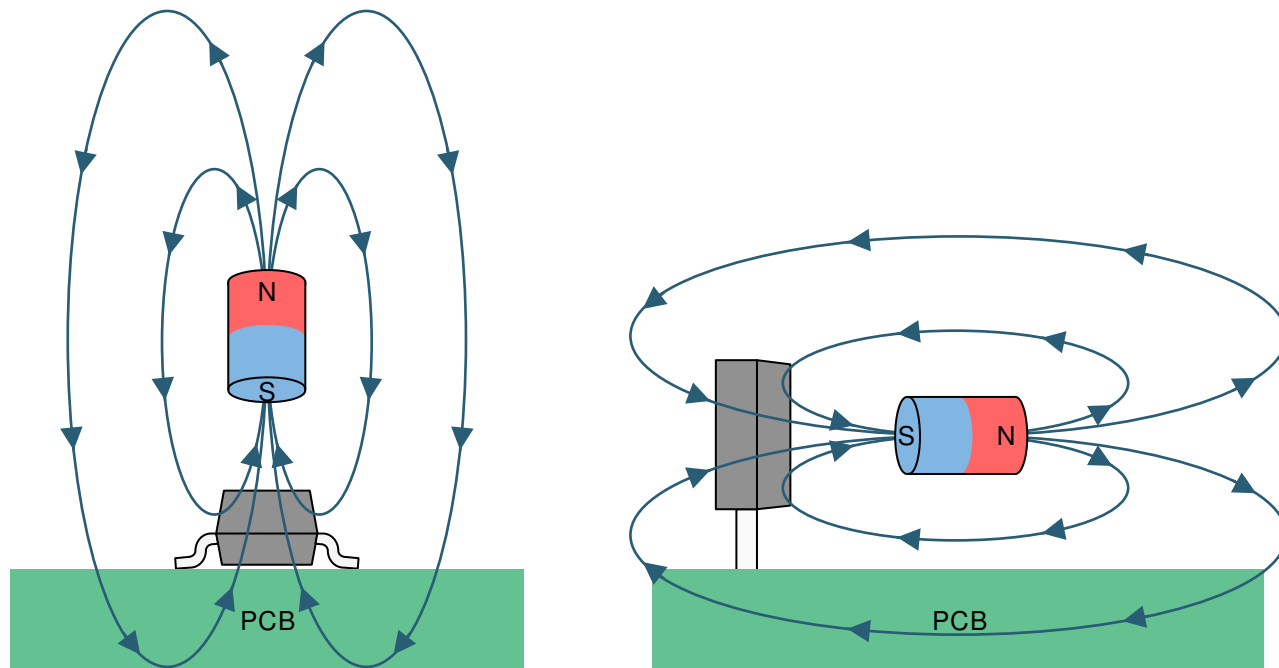


Figure 7-2. The Flux Direction for Positive B

7.3.2 Magnetic Response

When the DRV5055 is powered, the DRV5055 outputs an analog voltage according to [Equation 1](#):

$$V_{OUT} = V_Q + B \times (\text{Sensitivity}_{(25^\circ\text{C})} \times (1 + S_{TC} \times (T_A - 25^\circ\text{C}))) \quad (1)$$

where

- V_Q is typically half of V_{CC}
- B is the applied magnetic flux density
- $\text{Sensitivity}_{(25^\circ\text{C})}$ depends on the device option and V_{CC}
- S_{TC} is typically 0.12%/°C for device options DRV5055A1 - DRV5055A4 and is 0%/°C for DRV5055Z1 - DRV5055Z4 options
- T_A is the ambient temperature
- V_{OUT} is within the V_L range

As an example, consider the DRV5055A3 with $V_{CC} = 3.3\text{ V}$, a temperature of 50°C , and 67 mT applied. Excluding tolerances, $V_{OUT} = 1650\text{ mV} + 67\text{ mT} \times (15\text{ mV/mT} \times (1 + 0.0012/^\circ\text{C} \times (50^\circ\text{C} - 25^\circ\text{C}))) = 2685\text{ mV}$.

7.3.3 Sensitivity Linearity

The device produces a linear response when the output voltage is within the specified V_L range. Outside this range, sensitivity is reduced and nonlinear. Figure 7-3 graphs the magnetic response.

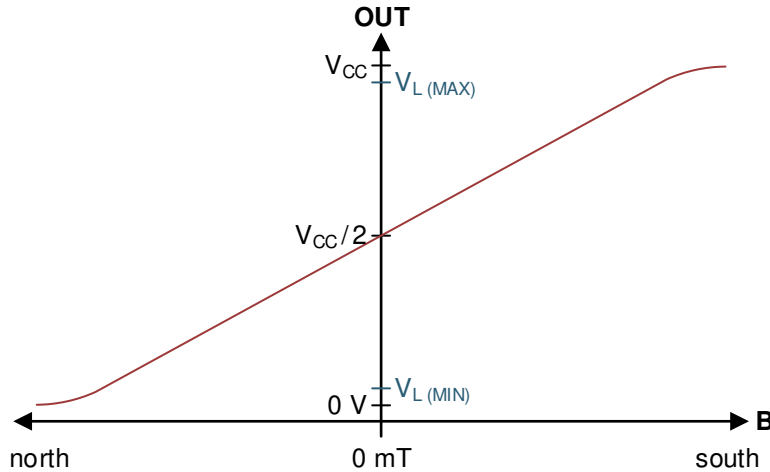


Figure 7-3. Magnetic Response

Equation 2 calculates parameter B_L , the minimum linear sensing range at 25°C taking into account the maximum quiescent voltage and sensitivity tolerances.

$$B_{L(MIN)} = \frac{V_{L(MAX)} - V_{Q(MAX)}}{S_{(MAX)}} \quad (2)$$

The parameter S_{LE} defines linearity error as the difference in sensitivity between any two positive B values, and any two negative B values, while the output is within the V_L range.

The parameter S_{SE} defines symmetry error as the difference in sensitivity between any positive B value and the negative B value of the same magnitude, while the output voltage is within the V_L range.

7.3.4 Ratiometric Architecture

The DRV5055 has a ratiometric analog architecture that scales the quiescent voltage and sensitivity linearly with the power-supply voltage. For example, the quiescent voltage and sensitivity are 5% higher when $V_{CC} = 5.25$ V compared to $V_{CC} = 5$ V. This behavior enables external ADCs to digitize a consistent value regardless of the power-supply voltage tolerance, when the ADC uses V_{CC} as its reference.

Equation 3 calculates the sensitivity ratiometry error:

$$S_{RE} = 1 - \frac{S_{(VCC)} / S_{(5V)}}{V_{CC} / 5V} \text{ for } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}, \quad S_{RE} = 1 - \frac{S_{(VCC)} / S_{(3.3V)}}{V_{CC} / 3.3V} \text{ for } V_{CC} = 3 \text{ V to } 3.63 \text{ V} \quad (3)$$

where

- $S_{(VCC)}$ is the sensitivity at the current V_{CC} voltage
- $S_{(5V)}$ or $S_{(3.3V)}$ is the sensitivity when $V_{CC} = 5$ V or 3.3 V
- V_{CC} is the current V_{CC} voltage

Equation 4 calculates quiescent voltage ratiometry error:

$$V_{QRE} = 1 - \frac{V_{Q(VCC)} / V_{Q(5V)}}{V_{CC} / 5V} \text{ for } V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}, \quad V_{QRE} = 1 - \frac{V_{Q(VCC)} / V_{Q(3.3V)}}{V_{CC} / 3.3V} \text{ for } V_{CC} = 3 \text{ V to } 3.63 \text{ V} \quad (4)$$

where

- $V_{Q(VCC)}$ is the quiescent voltage at the current V_{CC} voltage
- $V_{Q(5V)}$ or $V_{Q(3.3V)}$ is the quiescent voltage when $V_{CC} = 5 \text{ V}$ or 3.3 V
- V_{CC} is the current V_{CC} voltage

7.3.5 Operating V_{CC} Ranges

The DRV5055 has two recommended operating V_{CC} ranges: 3 V to 3.63 V and 4.5 V to 5.5 V . When V_{CC} is in the middle region between 3.63 V to 4.5 V , the device continues to function, but sensitivity is less known because there is a crossover threshold near 4 V that adjusts device characteristics.

7.3.6 Sensitivity Temperature Compensation for Magnets

Magnets generally produce weaker fields as temperature increases. The DRV5055 can either compensate by increasing sensitivity with temperature or by keeping the sensitivity constant, as defined by the parameters S_{TC} and S_{TCz} , respectively. For device options DRV5055A1 - DRV5055A4, the sensitivity at $T_A = 125^\circ\text{C}$ is typically 12% higher than at $T_A = 25^\circ\text{C}$. For device options DRV5055Z1 - DRV5055Z4, the sensitivity at $T_A = 125^\circ\text{C}$ is typically same as the value at $T_A = 25^\circ\text{C}$.

7.3.7 Power-On Time

After the V_{CC} voltage is applied, the DRV5055 requires a short initialization time before the output is set. The parameter t_{ON} describes the time from when V_{CC} crosses 3 V until OUT is within 5% of V_Q , with 0 mT applied and no load attached to OUT. Figure 7-4 shows this timing diagram.

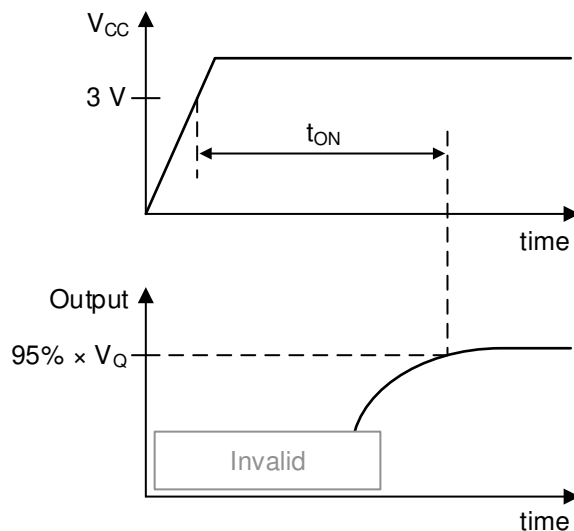


Figure 7-4. t_{ON} Definition

7.3.8 Hall Element Location

Figure 7-5 shows the location of the sensing element inside each package option.

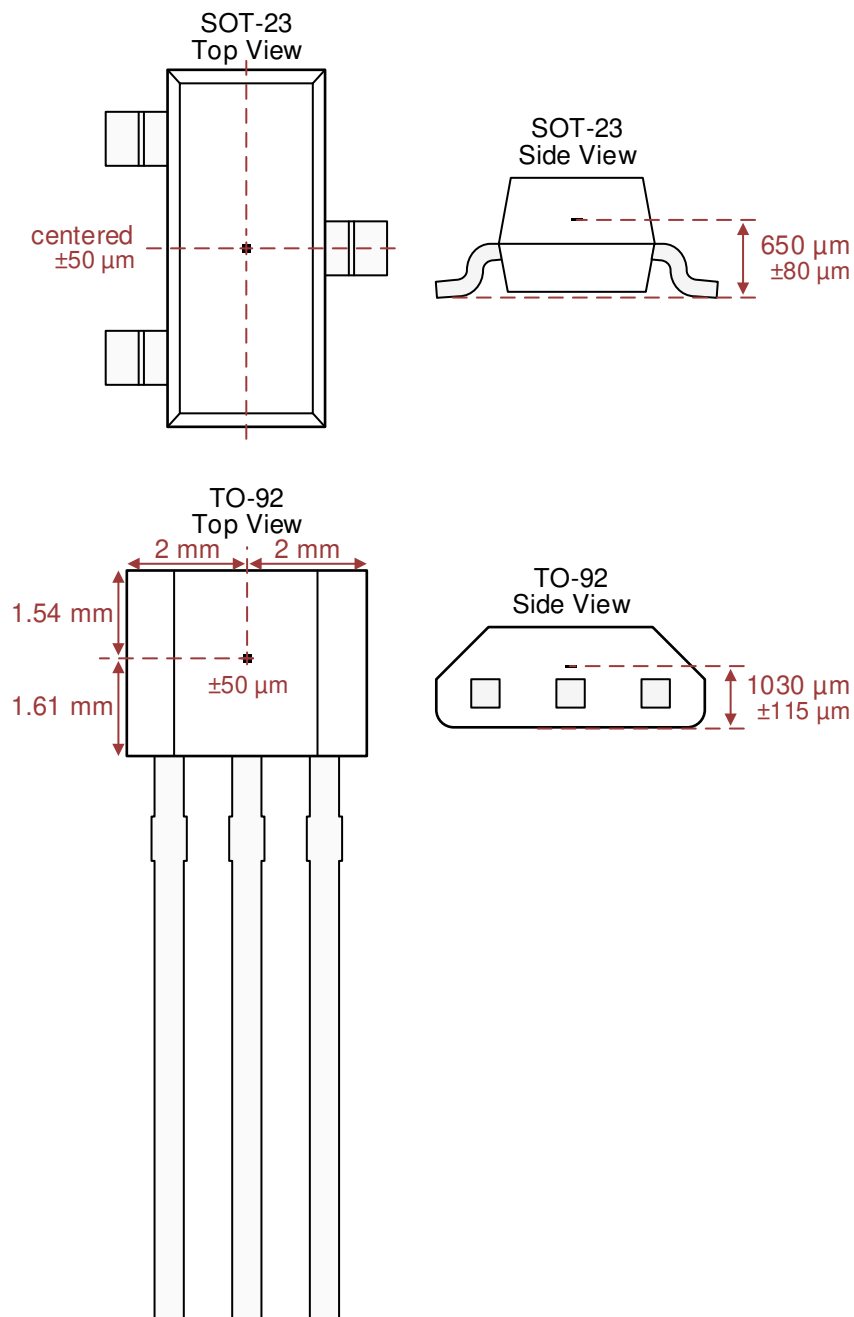


Figure 7-5. Hall Element Location

7.4 Device Functional Modes

The DRV5055 has one mode of operation that applies when the *Recommended Operating Conditions* are met.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Selecting the Sensitivity Option

Select the highest DRV5055 sensitivity option that can measure the required range of magnetic flux density, so that the output voltage swing is maximized.

Larger-sized magnets and farther sensing distances can generally enable better positional accuracy than very small magnets at close distances, because magnetic flux density increases exponentially with the proximity to a magnet. TI created an online tool to help with simple magnet calculations at <https://www.ti.com/product/drv5013>.

8.1.2 Temperature Compensation for Magnets

The DRV5055 temperature compensation is designed to directly compensate the average drift of neodymium (NdFeB) magnets and partially compensate ferrite magnets. The residual induction (B_r) of a magnet typically reduces by 0.12%/°C for NdFeB, and 0.20%/°C for ferrite. When the operating temperature of a system is reduced, temperature drift errors are also reduced.

8.1.3 Adding a Low-Pass Filter

As shown in [Functional Block Diagram](#), an RC low-pass filter can be added to the device output for the purpose of minimizing voltage noise when the full 20-kHz bandwidth is not needed. This filter can improve the signal-to-noise ratio (SNR) and overall accuracy. Do not connect a capacitor directly to the device output without a resistor in between because doing so can make the output unstable.

8.1.4 Designing for Wire Break Detection

Some systems must detect if interconnect wires become open or shorted. The DRV5055 can support this function.

First, select a sensitivity option that causes the output voltage to stay within the V_L range during normal operation. Second, add a pullup resistor between OUT and V_{CC} . TI recommends a value between 20 k Ω to 100 k Ω , and the current through OUT must not exceed the I_O specification, including current going into an external ADC. Then, if the output voltage is ever measured to be within 150 mV of V_{CC} or GND, a fault condition exists. [Figure 8-1](#) shows the circuit, and [Table 8-1](#) describes fault scenarios.

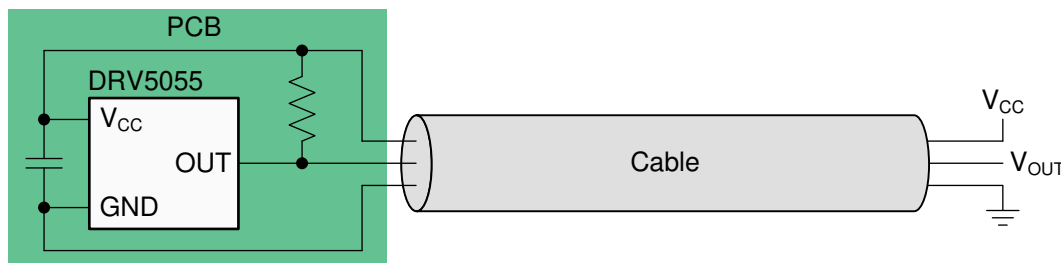


Figure 8-1. Wire Fault Detection Circuit

Table 8-1. Fault Scenarios and the Resulting V_{OUT}

FAULT SCENARIO	V_{OUT}
V_{CC} disconnects	Close to GND
GND disconnects	Close to V_{CC}
V_{CC} shorts to OUT	Close to V_{CC}
GND shorts to OUT	Close to GND

8.2 Typical Application

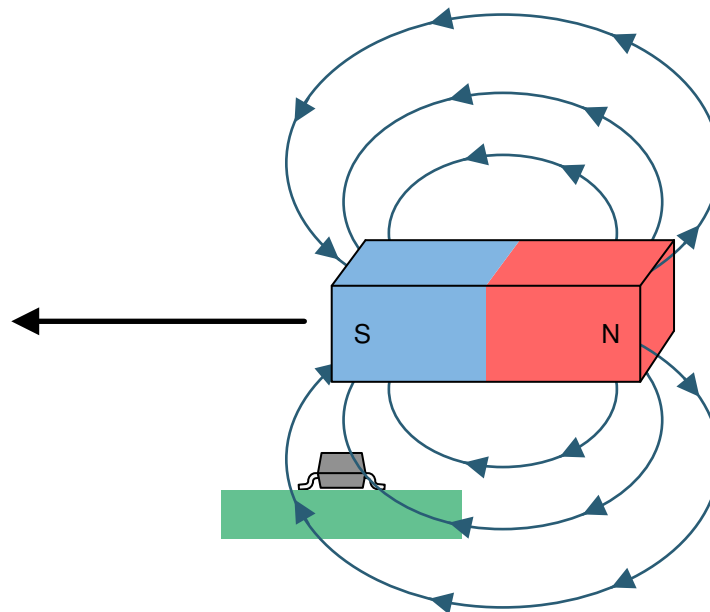


Figure 8-2. Common Magnet Orientation

8.2.1 Design Requirements

Use the parameters listed in [Table 8-2](#) for this design example.

Table 8-2. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
V_{CC}	5 V
Magnet	15 × 5 × 5 mm NdFeB
Travel distance	12 mm
Maximum B at the sensor at 25°C	±75 mT
Device option	DRV5055A3

8.2.2 Detailed Design Procedure

Linear Hall effect sensors provide flexibility in mechanical design, because many possible magnet orientations and movements produce a usable response from the sensor. [Figure 8-2](#) shows one of the most common orientations, which uses the full north to south range of the sensor and causes a close-to-linear change in magnetic flux density as the magnet moves across.

When designing a linear magnetic sensing system, always consider these three variables: the magnet, sensing distance, and the range of the sensor. Select the DRV5055 with the highest sensitivity that has a B_L (linear magnetic sensing range) that is larger than the maximum magnetic flux density in the application. To determine the magnetic flux density the sensor receives, TI recommends using magnetic field simulation software, referring to magnet specifications, and testing.

8.2.3 Application Curve

Figure 8-3 shows the simulated magnetic flux from a NdFeB magnet.

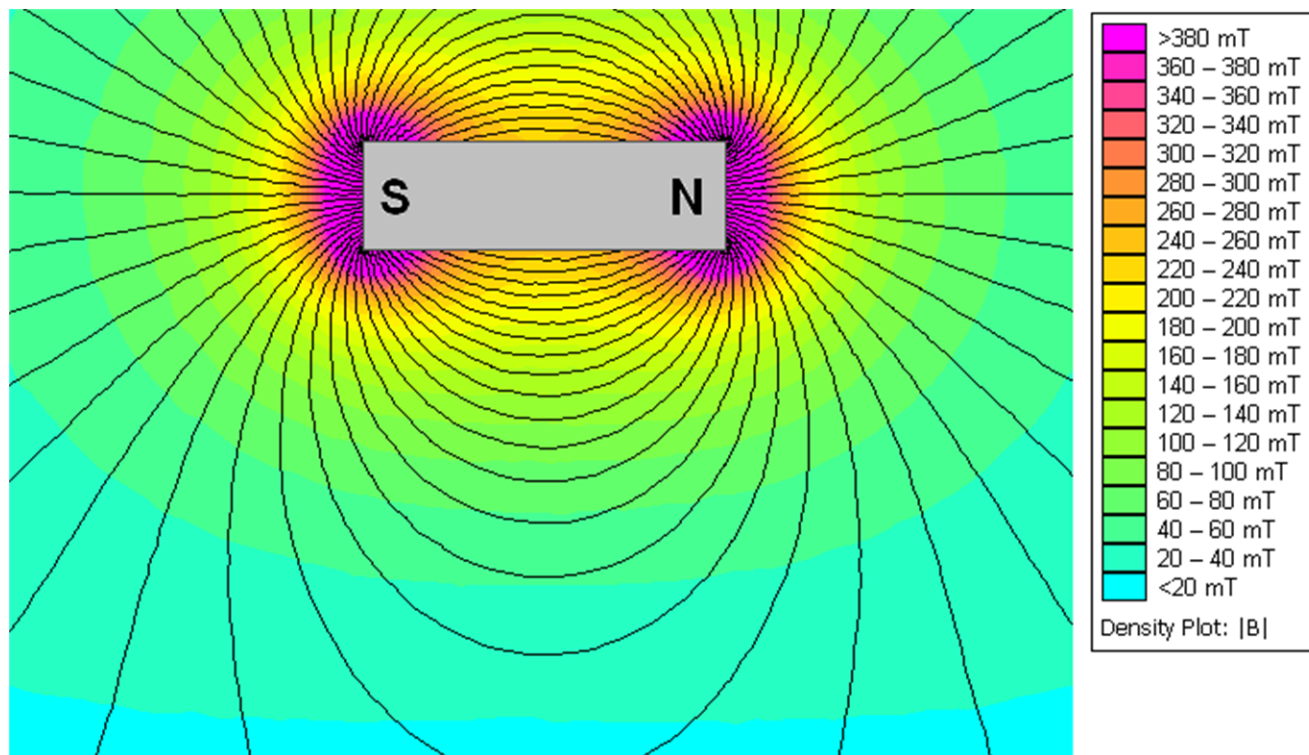


Figure 8-3. Simulated Magnetic Flux

8.3 Do's and Don'ts

Because the Hall element is sensitive to magnetic fields that are perpendicular to the top of the package, a correct magnet approach must be used for the sensor to detect the field. [Figure 8-4](#) shows correct and incorrect approaches.

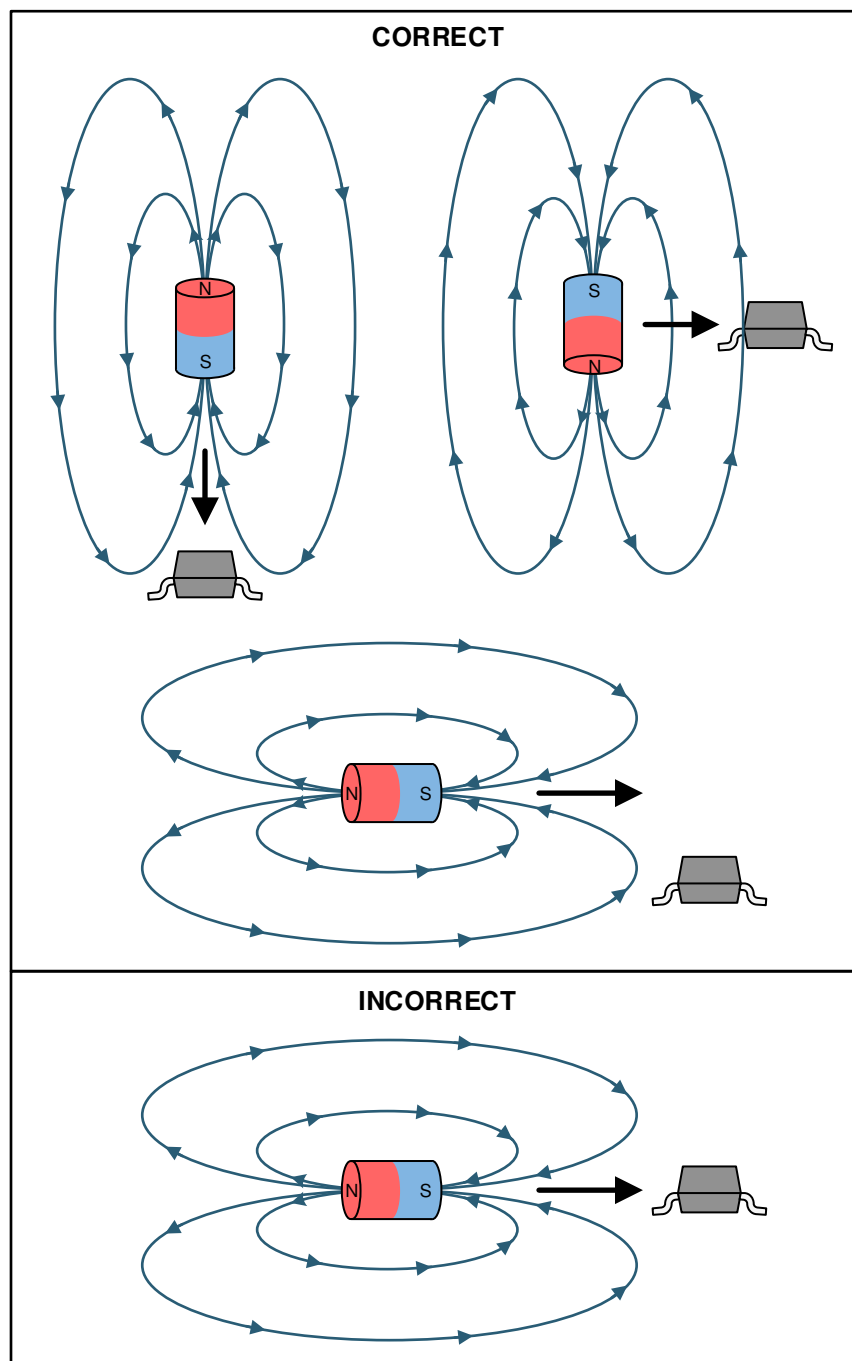


Figure 8-4. Correct and Incorrect Magnet Approaches

9 Power Supply Recommendations

A decoupling capacitor close to the device must be used to provide local energy with minimal inductance. TI recommends using a ceramic capacitor with a value of at least 0.01 μF .

10 Layout

10.1 Layout Guidelines

Magnetic fields pass through most nonferromagnetic materials with no significant disturbance. Embedding Hall effect sensors within plastic or aluminum enclosures and sensing magnets on the outside is common practice. Magnetic fields also easily pass through most printed-circuit boards, which makes placing the magnet on the opposite side possible.

10.2 Layout Examples

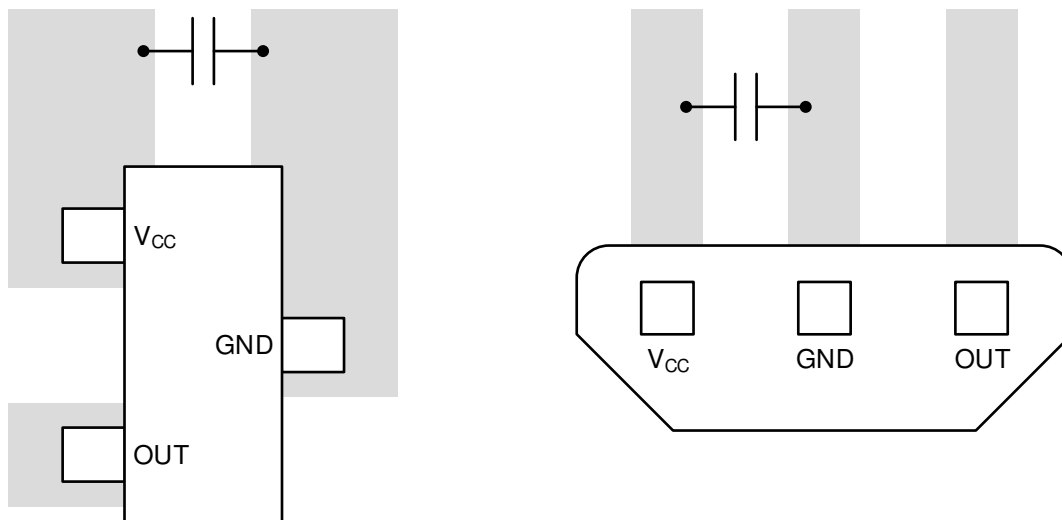


Figure 10-1. Layout Examples

11 Device and Documentation Support

11.1 Documentation Support

11.1.1 Related Documentation

For related documentation see the following:

- Texas Instruments, [Overview Using Linear Hall Effect Sensors to Measure Angle](#) application brief
- Texas Instruments, [Incremental Rotary Encoder Design Considerations](#) application brief

11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

11.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

11.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5055A1QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A1
DRV5055A1QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A1
DRV5055A1QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A1
DRV5055A1QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55A1
DRV5055A1QLPG	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A1QLPG.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A1QLPG.B	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A1QLPGM	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A1QLPGM.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A1QLPGM.B	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A1
DRV5055A2QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A2
DRV5055A2QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A2
DRV5055A2QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A2
DRV5055A2QLPG	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A2QLPG.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A2QLPG.B	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A2QLPGM	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A2QLPGM.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A2QLPGM.B	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A2
DRV5055A3QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A3
DRV5055A3QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A3
DRV5055A3QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A3
DRV5055A3QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55A3
DRV5055A3QLPG	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A3
DRV5055A3QLPG.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A3
DRV5055A3QLPG.B	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A3
DRV5055A3QLPGM	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A3
DRV5055A3QLPGM.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A3
DRV5055A3QLPGM.B	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A3

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5055A4QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A4
DRV5055A4QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A4
DRV5055A4QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55A4
DRV5055A4QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55A4
DRV5055A4QLPG	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055A4QLPG.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055A4QLPG.B	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055A4QLPGM	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055A4QLPGM.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055A4QLPGM.B	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	55A4
DRV5055Z1QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z1
DRV5055Z1QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z1
DRV5055Z1QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z1
DRV5055Z1QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55Z1
DRV5055Z2QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z2
DRV5055Z2QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z2
DRV5055Z2QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z2
DRV5055Z2QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55Z2
DRV5055Z3QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z3
DRV5055Z3QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z3
DRV5055Z3QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z3
DRV5055Z3QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55Z3
DRV5055Z4QDBZR	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z4
DRV5055Z4QDBZR.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z4
DRV5055Z4QDBZR.B	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	SN	Level-2-260C-1 YEAR	-40 to 125	55Z4
DRV5055Z4QDBZT	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	55Z4

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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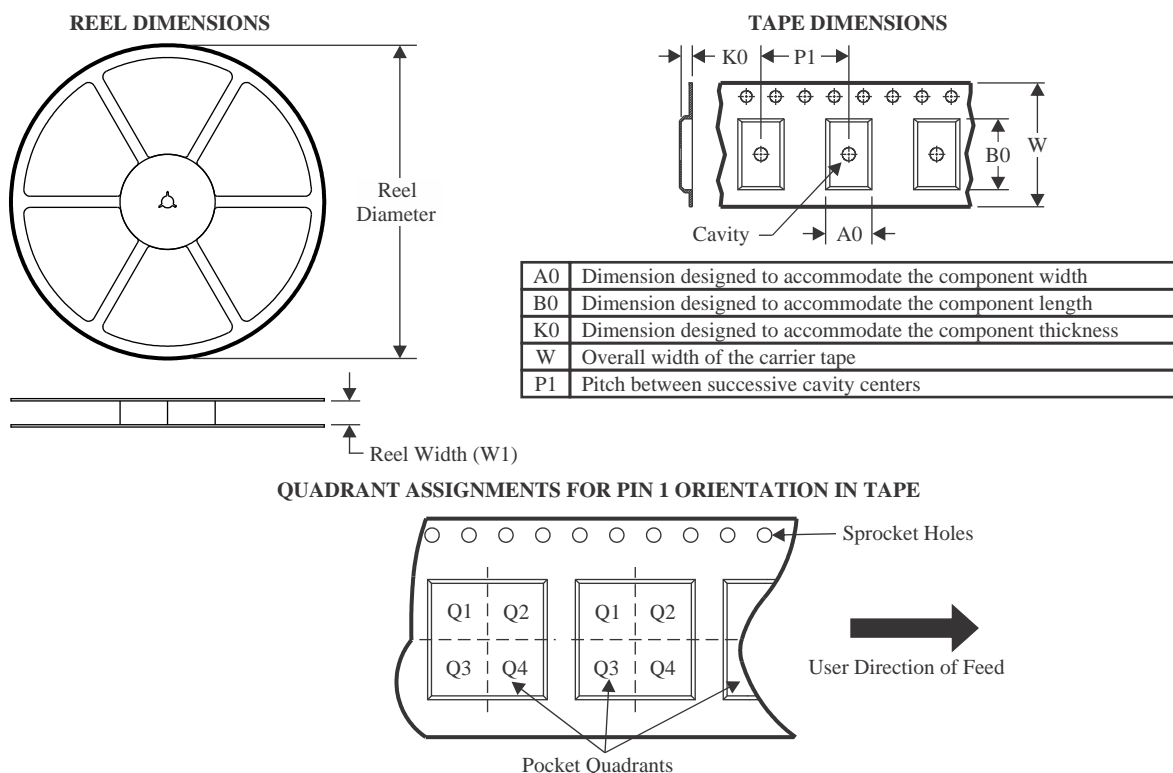
OTHER QUALIFIED VERSIONS OF DRV5055 :

- Automotive : [DRV5055-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

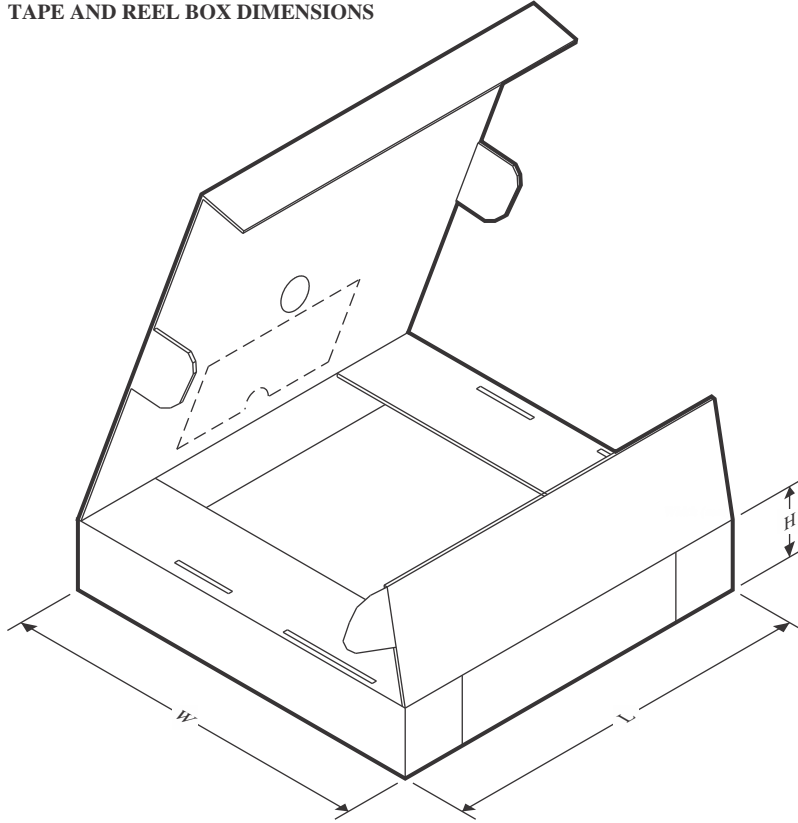
TAPE AND REEL INFORMATION



*All dimensions are nominal

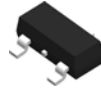
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DRV5055A1QDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
DRV5055A2QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055A3QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055A4QDBZR	SOT-23	DBZ	3	3000	178.0	9.0	3.15	2.77	1.22	4.0	8.0	Q3
DRV5055A4QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z1QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z1QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z2QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z3QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z3QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z4QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3
DRV5055Z4QDBZR	SOT-23	DBZ	3	3000	180.0	8.4	3.2	2.85	1.3	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS

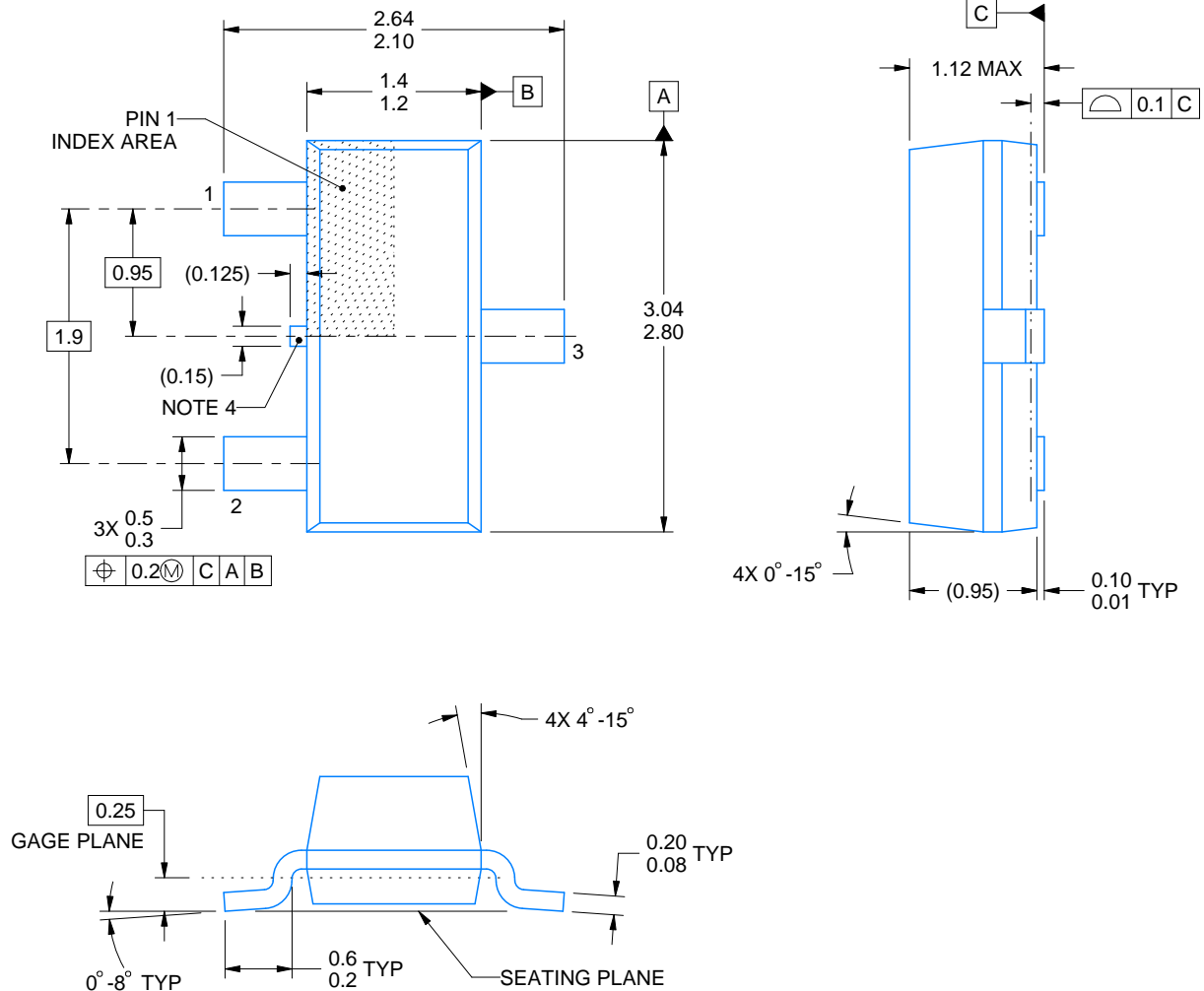


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DRV5055A1QDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
DRV5055A2QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055A3QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055A4QDBZR	SOT-23	DBZ	3	3000	180.0	180.0	18.0
DRV5055A4QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z1QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z1QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z2QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z3QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z3QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z4QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0
DRV5055Z4QDBZR	SOT-23	DBZ	3	3000	210.0	185.0	35.0

DBZ0003A**PACKAGE OUTLINE****SOT-23 - 1.12 mm max height**

SMALL OUTLINE TRANSISTOR



4214838/F 08/2024

NOTES:

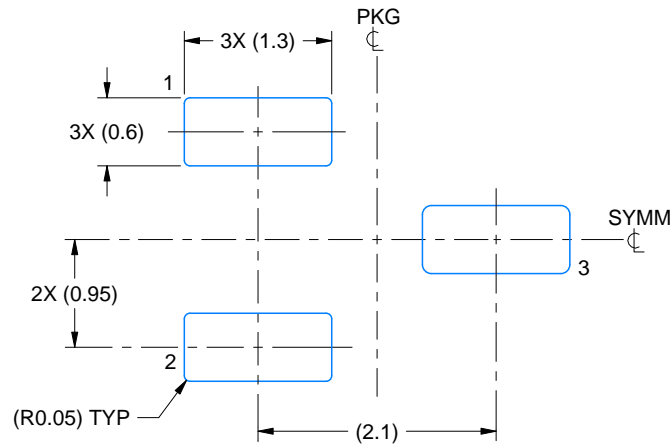
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

EXAMPLE BOARD LAYOUT

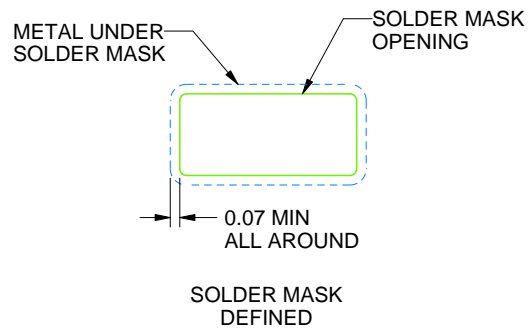
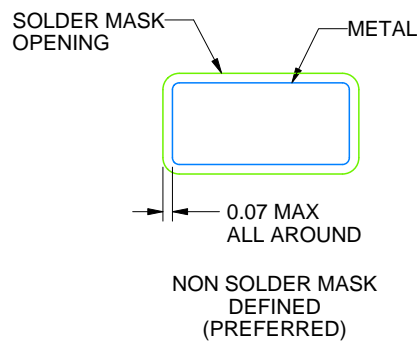
DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
SCALE:15X



SOLDER MASK DETAILS

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NOTES: (continued)

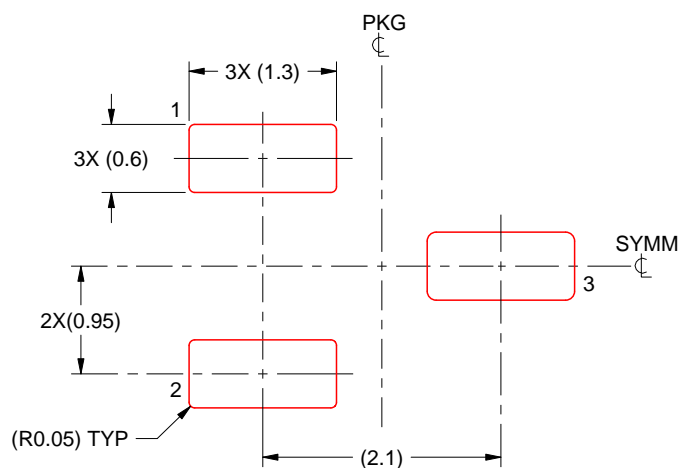
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/F 08/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

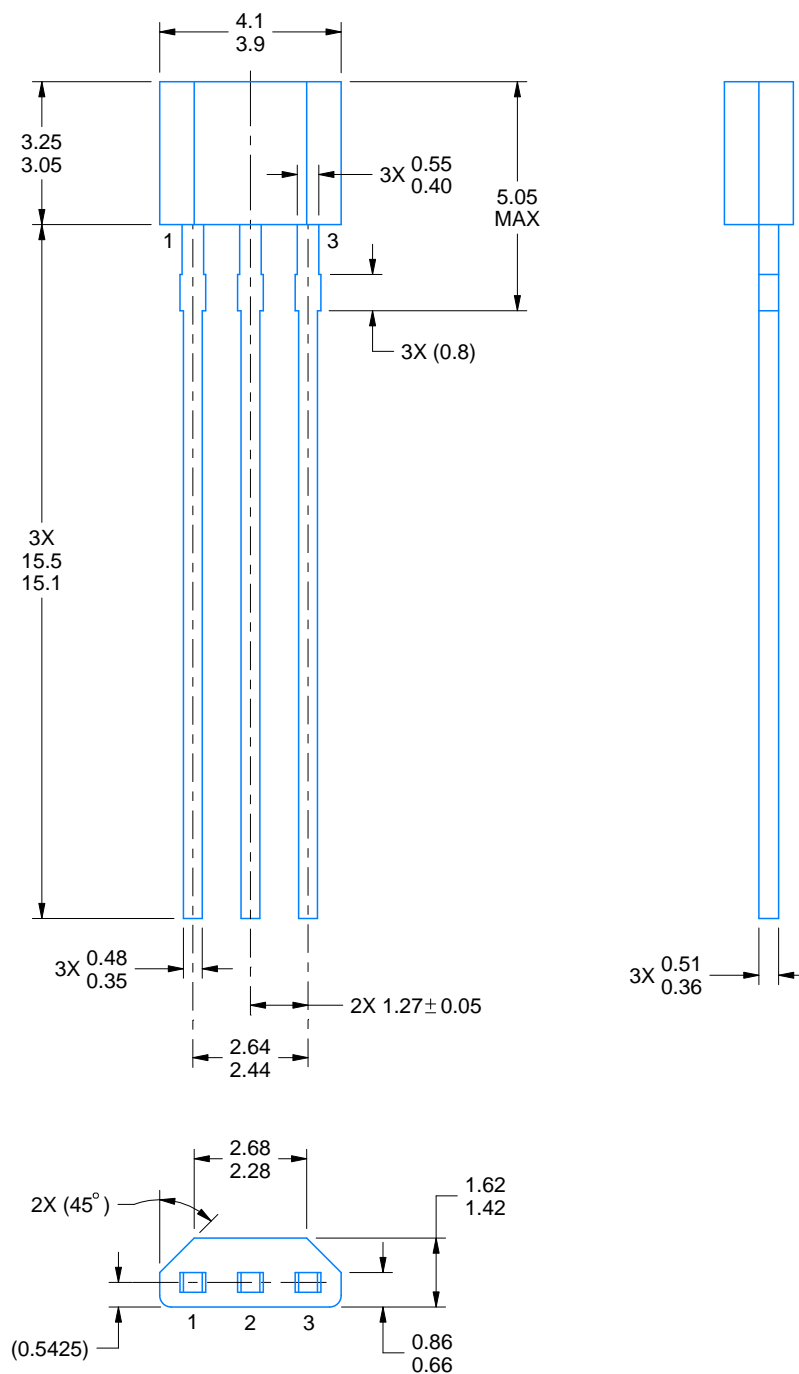
LPG0003A



PACKAGE OUTLINE

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



4221343/C 01/2018

NOTES:

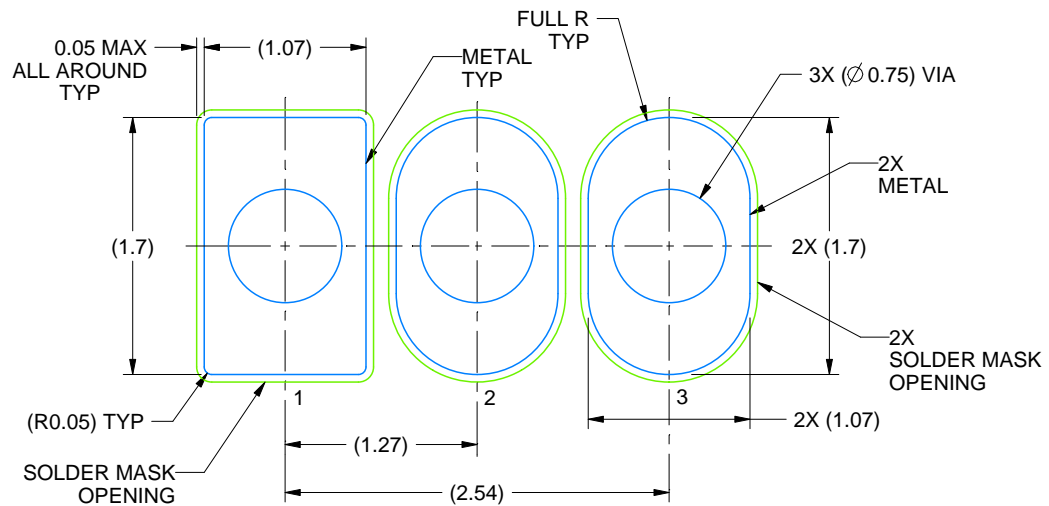
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE:20X

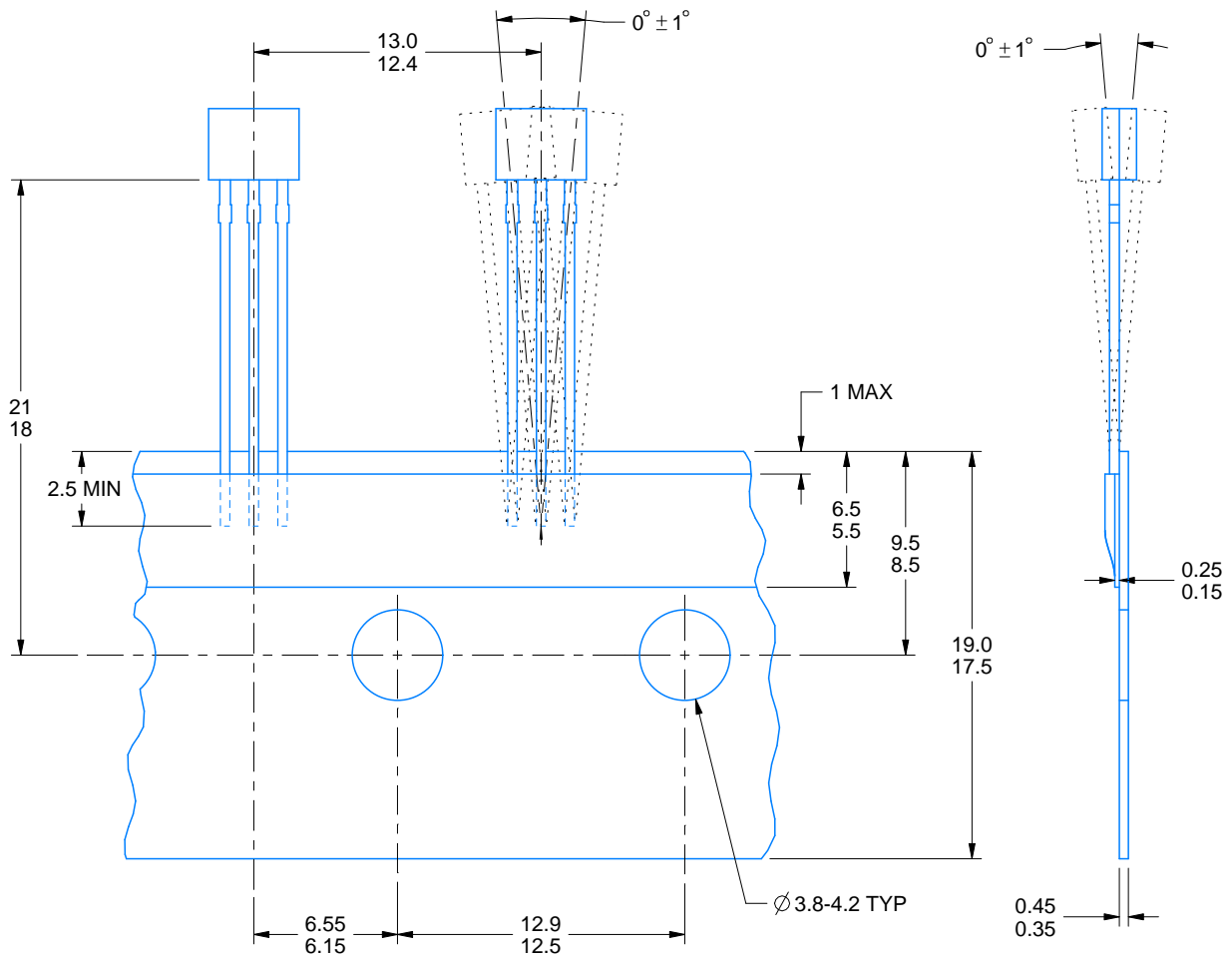
4221343/C 01/2018

TAPE SPECIFICATIONS

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



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